Phototransistor, top view type RPT-37PB3F

The RPT-37PB3F is a silicon planar phototransistor. Since it is molded in plastic with a visible light filter, there is almost no effect from stray light. It is particularly suited for use with a ROHM SIR-34ST3F infrared light emitting diode. It is possible to distinguish the polarity by the shape of ramp type.

Applications

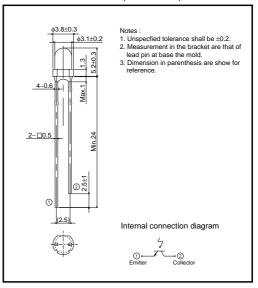
Optical control equipment Receiver for sensors

Features

1) High sensitivity.

2) Almost no effect from stray light.

•External dimensions (Units : mm)



•Absolute maximum ratings (Ta = 25°C)

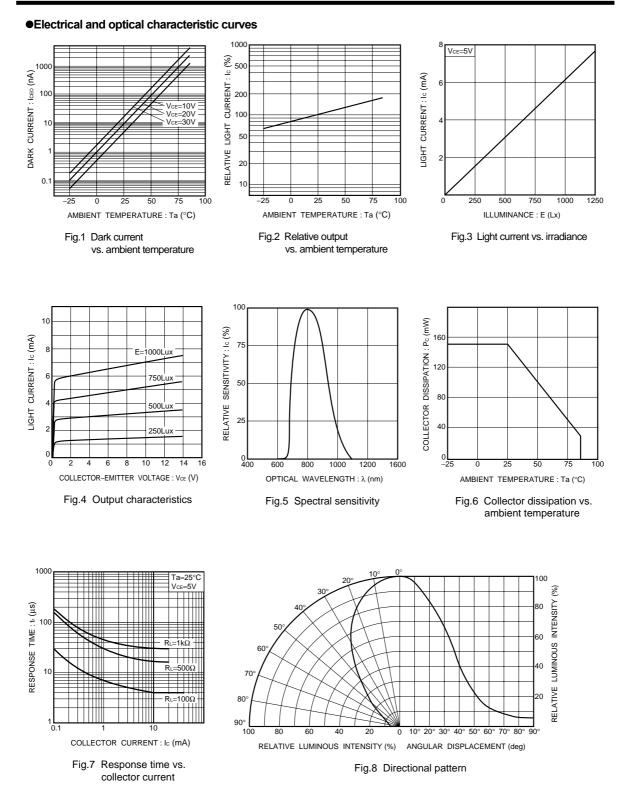
Parameter	Symbol	Limits	Unit
Collector-emitter voltage	Vceo	32	V
Emitter-collector voltage	Veco	5	V
Collector current	lc	30	mA
Collector power dissipation	Pc	150	mW
Operating temperature	Topr	-25~+85	°C
Storage temperature	Tstg	-30~+100	°C

•Electrical and optical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Light current	lc	2.0	-	-	mA	Vce=5V, E=500Lx
Dark current	ICEO	-	-	0.5	μA	V _{CE} =10V(Black box)
Peak sensitivity wavelength	λP	-	800	-	nm	_
Collector-emitter saturation voltage	VCE(sat)	-	-	0.4	V	Ic=1mA, E=500Lx
Half-angle	θ1/2	-	±36	-	deg	_
Response time	tr∙tſ	-	10	-	μs	Vcc=5V, Ic=1mA, R∟=100Ω



Sensors



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